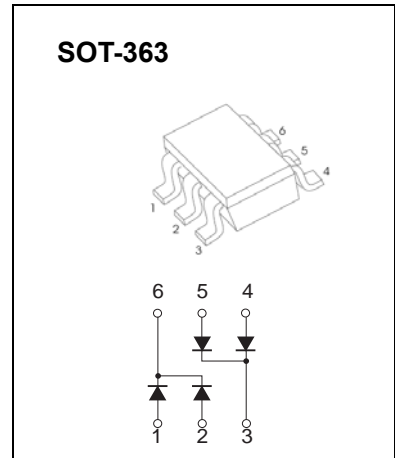


SOT-363 Plastic-Encapsulate Diodes

SWITCHING DIODE

FEATURES

- Fast Switching Speed
- Ultra-Small Surface Mount Package
- For General Purpose Switching Applications
- High Conductance
- **Pb-Free package is available**
RoHS product for packing code suffix "G"
Halogen free product for packing code suffix "H"
- **Moisture Sensitivity Level 1**



MAKING: KJA

Maximum Ratings @Ta=25°C

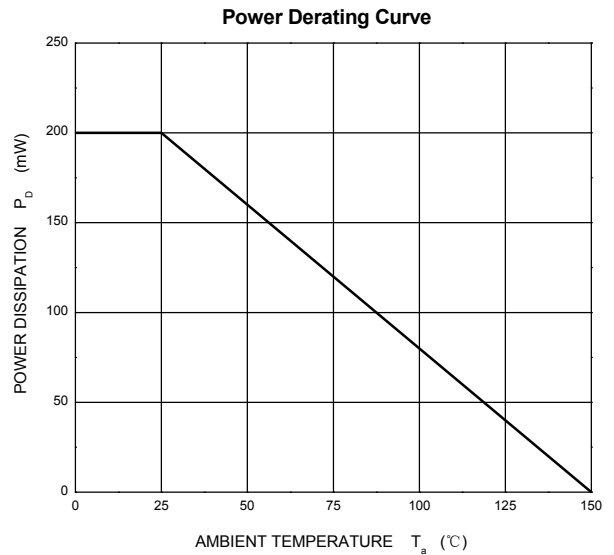
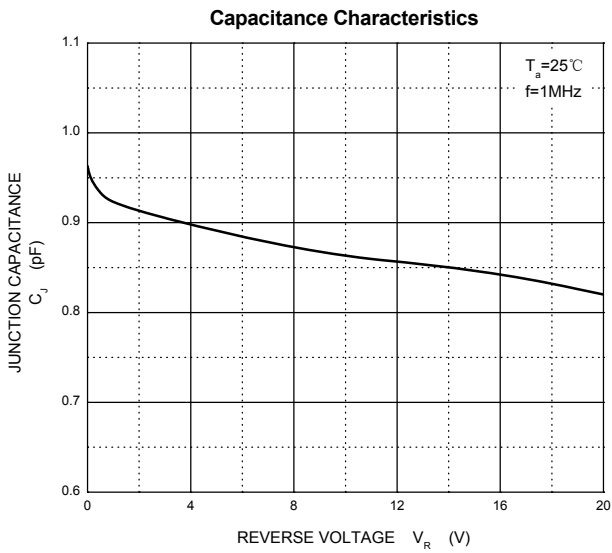
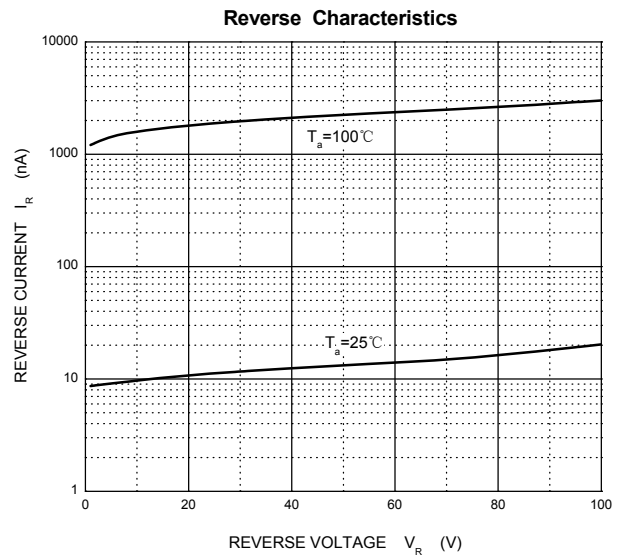
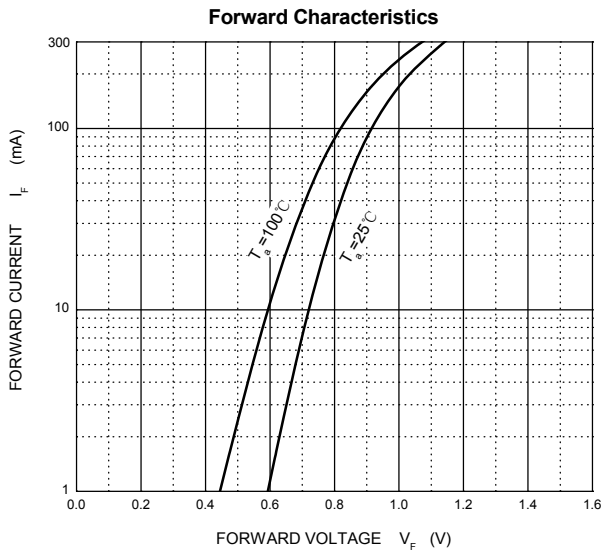
Parameter	Symbol	Limit	Unit
Peak Repetitive Peak Reverse Voltage	V_{RRM}	100	V
Working Peak Reverse Voltage	V_{RWM}	100	
DC Blocking Voltage	V_R	75	
Forward Continuous Current	I_{FM}	300	mA
Average Rectified Output Current	I_O	150	mA
Non-Repetitive Peak Forward Surge Current	I_{FSM}	@ t = 1.0µs 2	A
		@ t = 1.0s 1	
Power Dissipation	P_D	200	mW
Thermal Resistance Junction to Ambient	$R_{\theta JA}$	625	°C/W
Operating Junction Temperature	T_J	150	°C
Storage Temperature	T_{STG}	-55~+150	°C

ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Max	Unit
Reverse breakdown voltage	$V_{(BR)}$	$I_R = 2.5\mu A$	75		V
Reverse voltage leakage current	I_R	$V_R = 75V$ $V_R = 20V$		2.5 0.025	µA
Forward voltage	V_F	$I_F = 1mA$ $I_F = 10mA$ $I_F = 50mA$ $I_F = 150mA$		715 855 1000 1250	mV
Junction capacitance	C_j	$V_R = 0, f = 1MHz$		2	pF
Reveres recovery time	t_{rr}	$I_F = I_R = 10mA, I_{tr} = 0.1 \times I_R,$ $R_L = 100\Omega$		4	ns



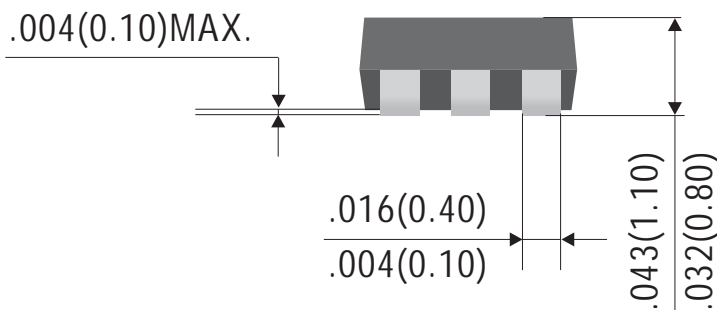
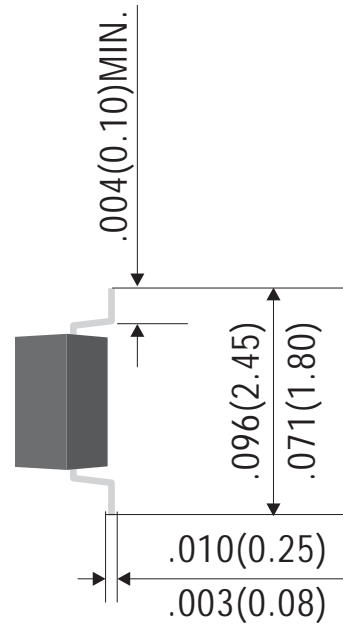
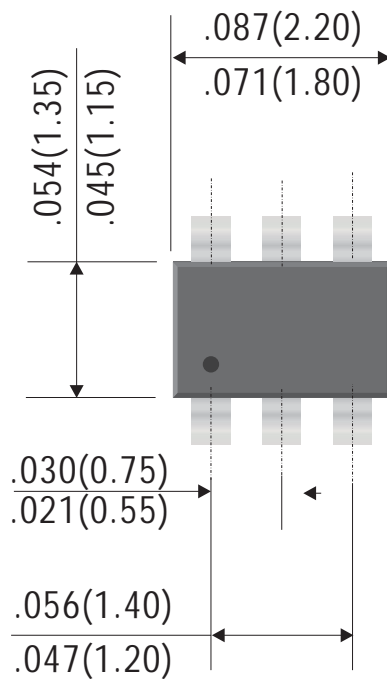
Typical Characteristics





Outline Drawing

SOT-363



Dimensions in inches and (millimeters)